EYP-BAL-0670-00001-1510-SOT23-0010



BROAD AREA LASER Image: 1 of 4 GaAs Semiconductor Laser Diode Image: 2 million of the semiconductor Laser Diode Single Emitter Structure Image: 2 million of the semiconductor Laser Diode

General Product Information		
Product	Application	
670 nm Broad Area Laser	Sensing	
for Pulse Mode Operation		
sealed TO Housing		

Absolute Maximum Ratings

	Symbol	Unit	min	typ	max
Storage Temperature	Ts	°C	-40		85
Operational Temperature at Case	T _C	°C	-35		80
Peak Current	I _{F Peak}	А			3.0
Reverse Voltage	V _R	V			2
Peak Output Power	P _{opt Peak}	W			2.4
Forward Voltage at Peak	V _F	V			2.7

Recommended Operational Conditions (Pulse Mode)

	Symbol	Unit	min	typ	max
Operational Temperature at Case	T _C	°C	15		40
Forward Current	I _{F Peak}	А			2.4
Output Power	P _{opt Peak}	W		1.8	

Characteristics at T_{amb} 25 °C, Pulse Mode, Begin Of Life

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	λ_{C}	nm	660	670	680
Spectral Width (FWHM)	Δλ	nm		4	6
Temperature Coefficient of Wavelength	dλ / dT	nm / K		0.18	
Peak Output Power @ $I_F = 2.4 A$	P _{opt Peak}	W		1.8	
Threshold Current	I _{th}	А		0.5	
Differential Series Resistance	Rs	Ω		0.1	
Slope Efficiency	n	W/A		1.0	



Every condition of the Absolute Maximum Ratings has to be kept during operation
see Pulse Mode Conditions, @ 25° C
see Pulse Mode Conditions
see Pulse Mode Conditions

Measurement Conditions / Comments				
see Pulse Mode Conditions, @ 25° C				
see Pulse Mode Conditions				

see Pul	se Mode	Condition	ıs	
see Pul	se Mode	Conditio	าร	

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BROAD AREA LASER

GaAs Semiconductor Laser Diode Single Emitter Structure



Characteristics at T_{amb} 25 °C, Pulse Mode, Begin Of Life

Parameter	Symbol	Unit	min	typ	max
Cavity Length	L	μm		1500	
Stripe width	Ws	μm		100	
Divergence parallel (FWHM)	$\Theta_{ }$	0		10	
Divergence perpendicular (FWHM)	Θ_{\perp}	0		30	
Polarization				TE	
Spectral Mode (longitudinal)				Multi Mode	

Measurement Conditions / Comments				
E field parallel to Pin 2 - Pin 3 - plane				

Pulse Mode Conditions

Parameter	Symbol	Unit	min	typ	max
Pulse Length	t _p	μs		10	
Pulse Repetition Rate	RR_{p}	s ⁻¹		5000	

Measurement Conditions / Comments

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GaAs Semiconductor Laser Diode Single Emitter Structure

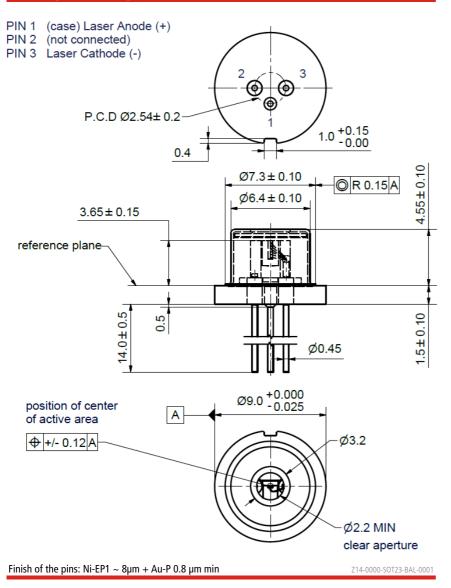
Package Dimensions

Parameter	Symbol	Unit	min	typ	max
Height of Emission Plane	d _{EP}	mm		3.65	
Excentricity of Emission Center	R	mm			0.12
Pin Length	Ι	mm		14.0	

Measurement Conditions / Comments reference plane A: top side of TO header

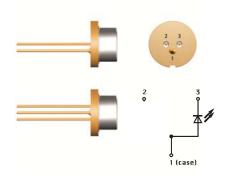
reference B: center of outer diameter of header

Package Drawings



Pinout

Revision 0.70



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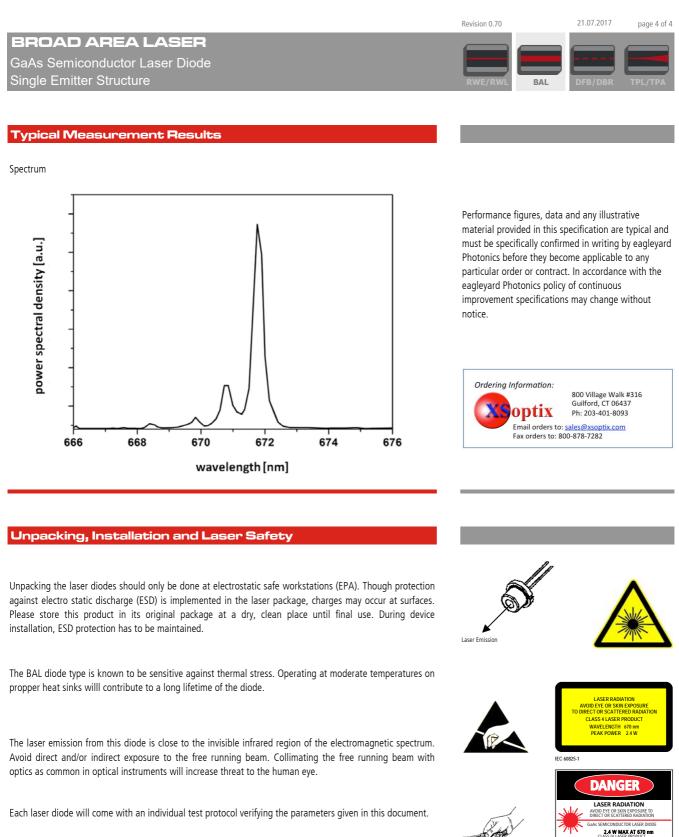


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